

MCH3486

Power MOSFET 60V, 137mΩ, 2A, Single N-Channel



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Features

- Low $R_{DS(on)}$
- 4V Drive
- ESD Diode-Protected Gate
- Pb-Free, Halogen Free and RoHS Compliance
- Small Surface Mount Package (MCPH3)

Specifications

Absolute Maximum Ratings at $T_a = 25^\circ\text{C}$

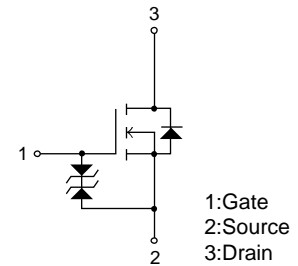
Parameter	Symbol	Value	Unit
Drain to Source Voltage	V_{DSS}	60	V
Gate to Source Voltage	V_{GSS}	± 20	V
Drain Current (DC)	I_D	2	A
Drain Current (Pulse) $PW \leq 10\mu\text{s}$, duty cycle $\leq 1\%$	I_{DP}	8	A
Power Dissipation When mounted on ceramic substrate ($900\text{mm}^2 \times 0.8\text{mm}$)	P_D	1	W
Junction Temperature	T_j	150	$^\circ\text{C}$
Storage Temperature	T_{stg}	-55 to +150	$^\circ\text{C}$

Thermal Resistance Ratings

Parameter	Symbol	Value	Unit
Junction to Ambient When mounted on ceramic substrate ($900\text{mm}^2 \times 0.8\text{mm}$)	$R_{\theta JA}$	125	$^\circ\text{C/W}$

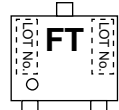
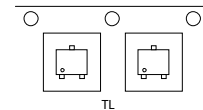
V_{DSS}	$R_{DS(on)}$ Max	I_D Max
60V	137 mΩ@10V	2A
	192 mΩ@4.5V	
	217 mΩ@4V	

Electrical Connection N-Channel



Packing Type: TL

Marking



Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

ORDERING INFORMATION

See detailed ordering and shipping information on page 5 of this data sheet.

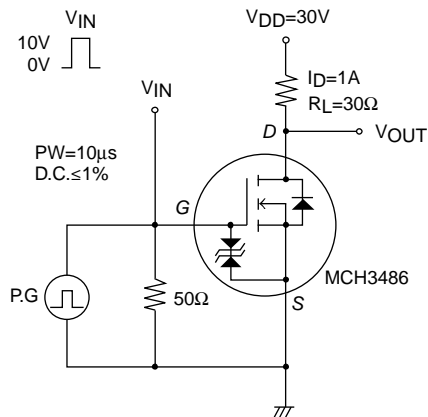
MCH3486

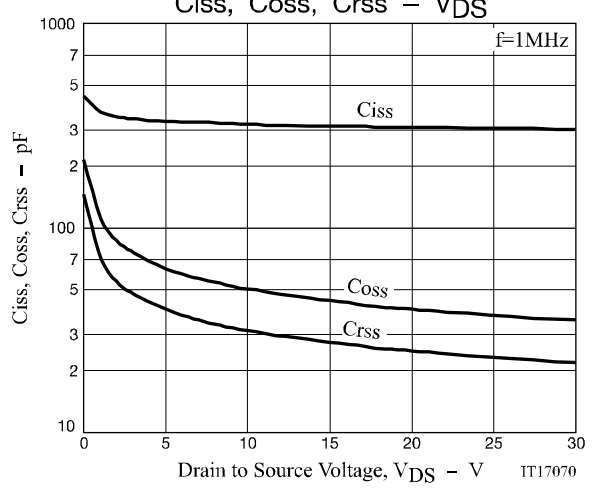
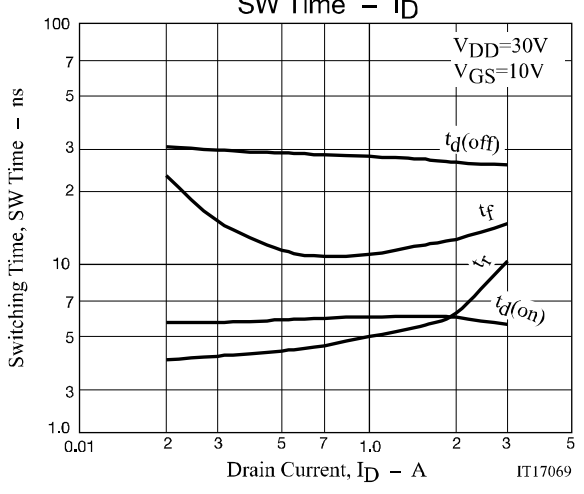
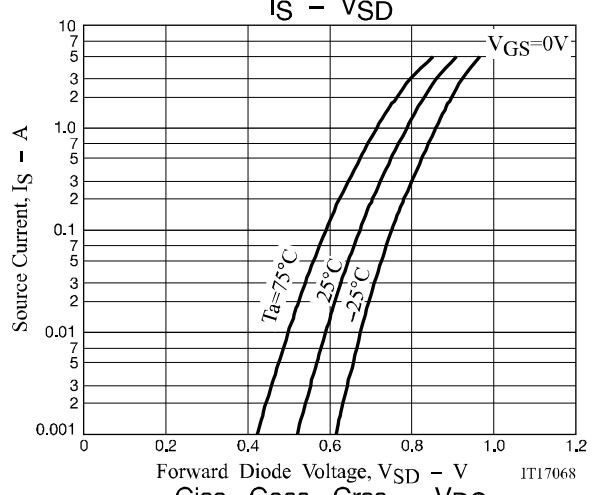
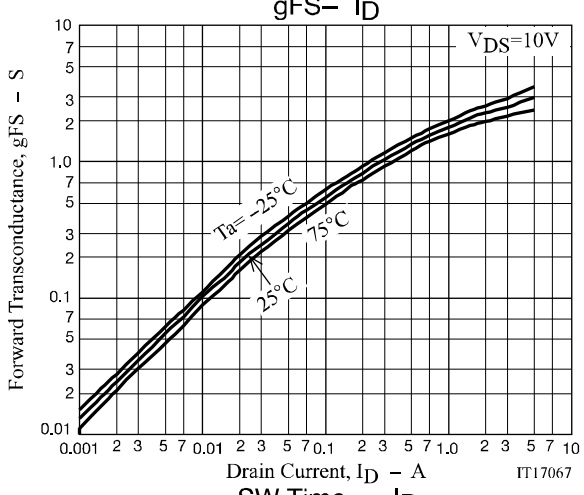
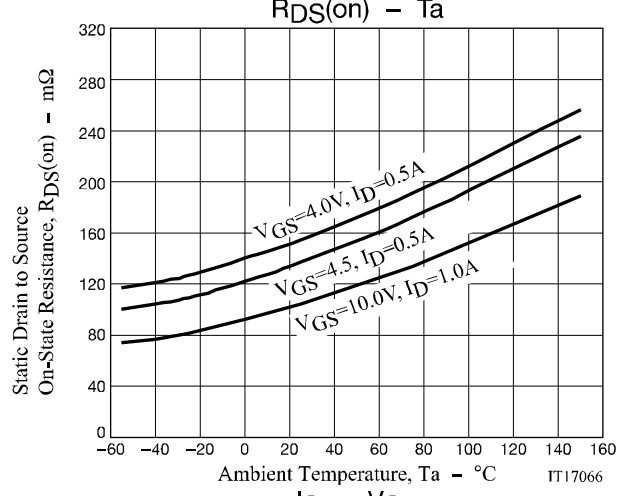
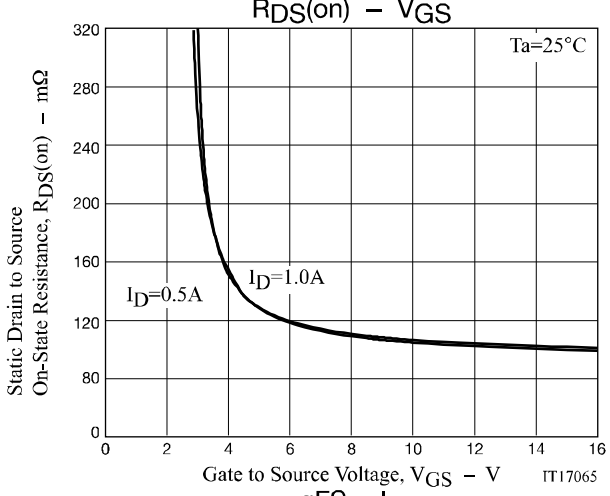
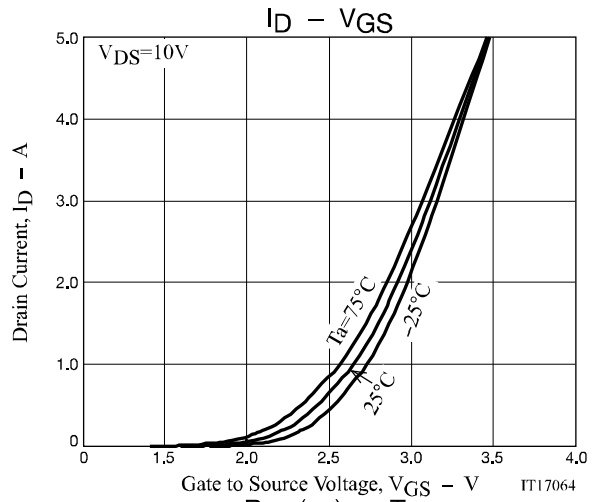
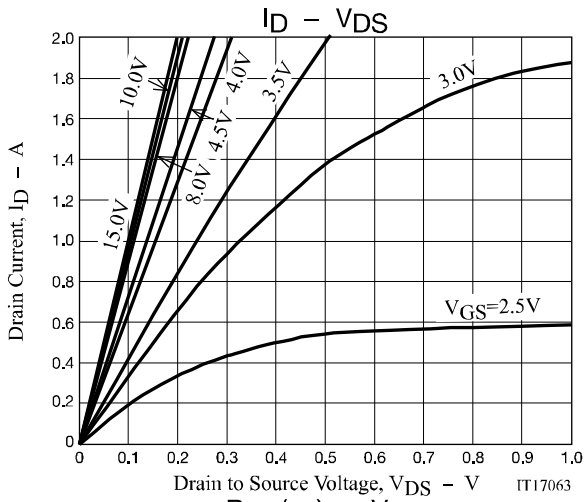
Electrical Characteristics at $T_a = 25^\circ\text{C}$

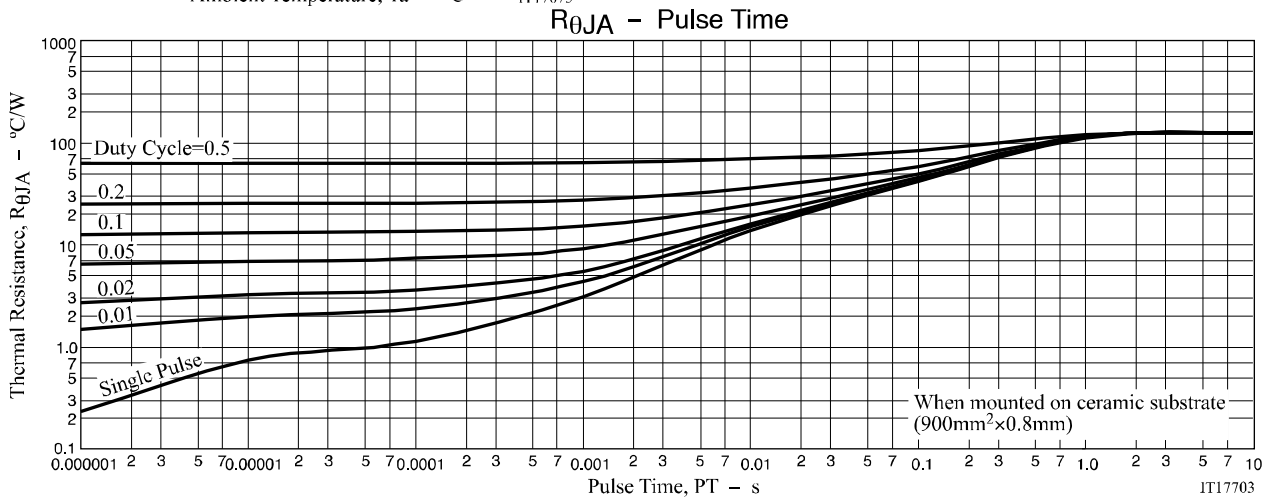
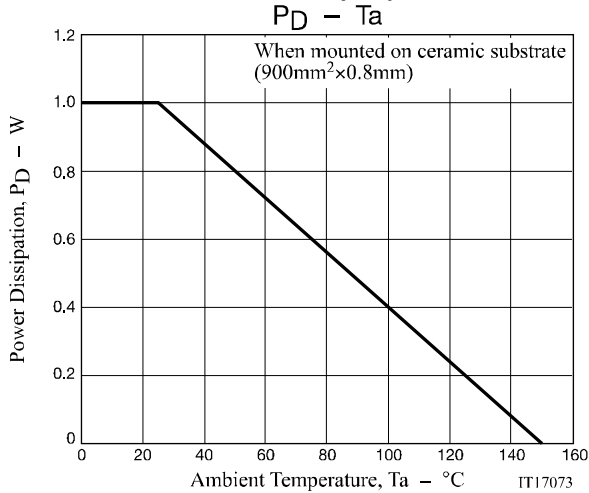
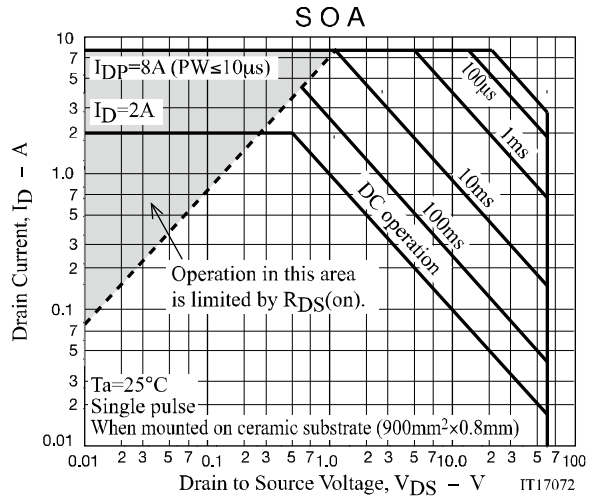
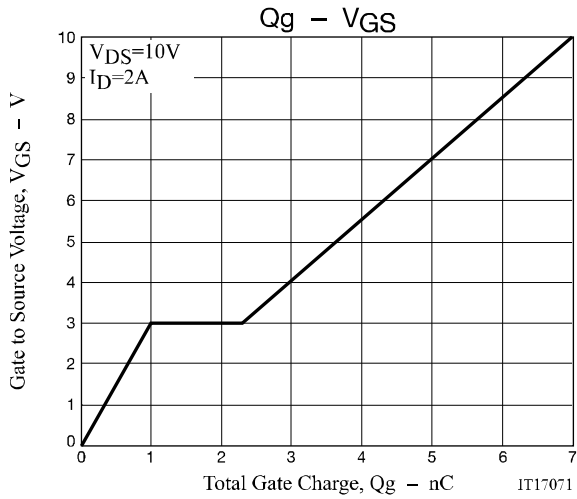
Parameter	Symbol	Conditions	Value			Unit
			min	typ	max	
Drain to Source Breakdown Voltage	$V_{(BR)DSS}$	$I_D=1\text{mA}, V_{GS}=0\text{V}$	60			V
Zero-Gate Voltage Drain Current	I_{DSS}	$V_{DS}=60\text{V}, V_{GS}=0\text{V}$			1	μA
Gate to Source Leakage Current	I_{GSS}	$V_{GS}=\pm 16\text{V}, V_{DS}=0\text{V}$			± 10	μA
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=10\text{V}, I_D=1\text{mA}$	1.2		2.6	V
Forward Transconductance	g_{FS}	$V_{DS}=10\text{V}, I_D=1\text{A}$		1.8		S
Static Drain to Source On-State Resistance	$R_{DS(on)1}$	$I_D=1\text{A}, V_{GS}=10\text{V}$		105	137	$\text{m}\Omega$
	$R_{DS(on)2}$	$I_D=0.5\text{A}, V_{GS}=4.5\text{V}$		137	192	$\text{m}\Omega$
	$R_{DS(on)3}$	$I_D=0.5\text{A}, V_{GS}=4\text{V}$		155	217	$\text{m}\Omega$
Input Capacitance	C_{iss}	$V_{DS}=20\text{V}, f=1\text{MHz}$		310		pF
Output Capacitance	C_{oss}			40		pF
Reverse Transfer Capacitance	C_{rss}			25		pF
Turn-ON Delay Time	$t_{d(on)}$			6		ns
Rise Time	t_r	See specified Test Circuit		5		ns
Turn-OFF Delay Time	$t_{d(off)}$			28		ns
Fall Time	t_f			11		ns
Total Gate Charge	Q_g	$V_{DS}=30\text{V}, V_{GS}=10\text{V}, I_D=2\text{A}$		7		nC
Gate to Source Charge	Q_{gs}			1		nC
Gate to Drain "Miller" Charge	Q_{gd}			1.3		nC
Forward Diode Voltage	V_{SD}		$I_S=2\text{A}, V_{GS}=0\text{V}$		0.83	1.2

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

Switching Time Test Circuit







MCH3486

Package Dimensions

MCH3486-TL-H/ MCH3486-TL-W

MCPH3

CASE 419AQ

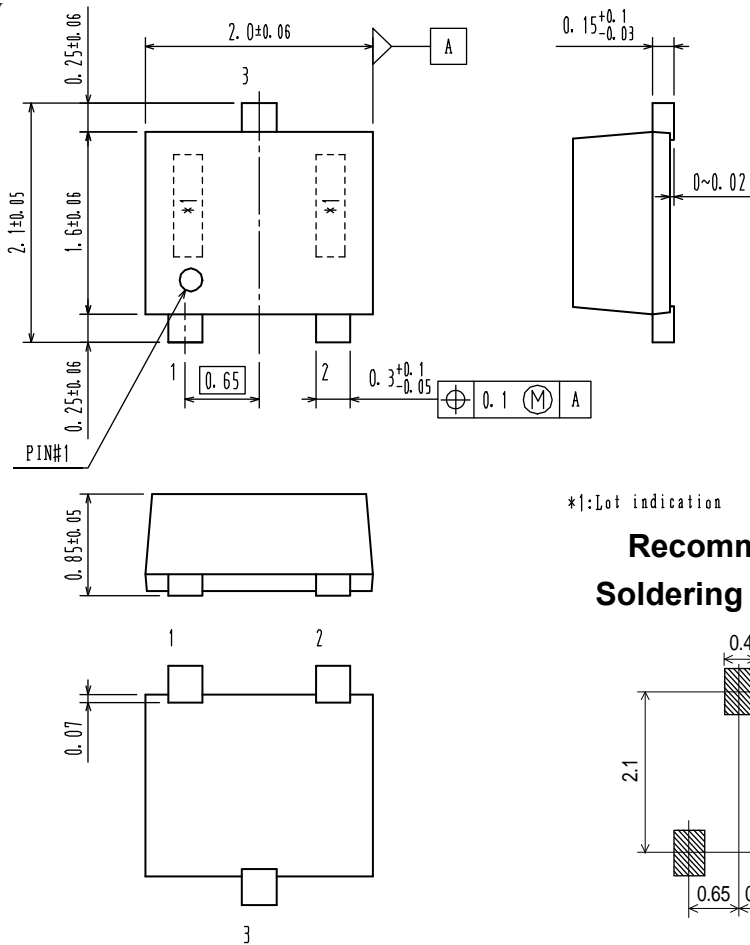
ISSUE O

Unit : mm

1 : Gate

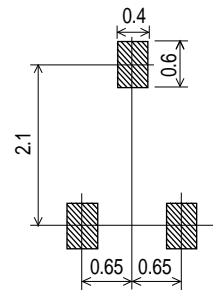
2 : Source

3 : Drain



*1: Lot indication

Recommended Soldering Footprint



Ordering & Package Information

Device	Package	Shipping	Note
MCH3486-TL-H	MCPH3	3,000 pcs. / reel	Pb-Free and Halogen Free
MCH3486-TL-W	SC-70,SOT-323		

Note on usage : Since the MCH3486 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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